DESCRIPTION

The EPC9507 is a high efficiency, Zero Voltage Switching (ZVS), Class-D Wireless Power amplifier demonstration board operating at 6.78 MHz (Lowest ISM band). The purpose of this demonstration system is to simplify the evaluation process of wireless power technology using eGaN® FETs by including all the critical components on a single board that can be easily connected into an existing system.

The amplifier board features the EPC2007C and EPC2038 enhancement mode field effect transistors (FET) in an optional half-bridge topology (single ended configuration) or default full-bridge topology (differential configuration), and includes the gate driver/s and oscillator that ensures operation of the system at 6.78 MHz. This revision of the wireless demonstration amplifier includes a synchronous bootstrap FET supply for the upper FETs of the ZVS Class-D amplifier that eliminates the reverse recovery losses of the gate driver’s internal bootstrap diode that dissipates energy in the upper FET. This circuit has been implemented using the new EPC2038 eGaN FET specifically designed for this function. To learn more about the synchronous bootstrap supply please refer to the following [1, 2, 3]. The EPC9507 amplifier board can also be operated using an external oscillator or by using the included ultra low power oscillator.

This revision can operate in either Single ended or Differential mode by changing a jumper setting. This allows for high efficiency operation with load impedance ranges that allow for single ended operation.

Finally, the timing adjust circuits for the ZVS Class-D amplifiers have been separated to further ensure highest possible efficiency setting and includes separate ZVS tank circuits.

The amplifier board is equipped with a pre-regulator that limits the DC current of the supply to the amplifier. As the amplifier draws more current, which can be due to the absence of a device coil, the pre-regulator will reduce the voltage being supplied to the amplifier that will ensure a safe operating point. The pre-regulator also monitors the temperature of the main amplifier FETs and will reduce current if the temperature exceeds 85°C. The pre-regulator can be bypassed to allow testing with custom control hardware. The board further allows easy access to critical measurement nodes that allow accurate power measurement instrumentation hookup. A simplified diagram of the amplifier board is given in Figure 1.

For more information on the EPC2007C or EPC2038 eGaN FET please refer to the datasheet available from EPC at www.epc-co.com. The data-sheet should be read in conjunction with this quick start guide.

Table 1: Performance Summary (TA = 25 °C) EPC9507

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Control Supply Input Range</td>
<td></td>
<td>7</td>
<td>12</td>
<td>V</td>
</tr>
<tr>
<td>$V_{IN}$</td>
<td>Bus Input Voltage Range – Pre-Regulator Mode</td>
<td></td>
<td>8</td>
<td>36</td>
<td>V</td>
</tr>
<tr>
<td>$I_{Osc_Disable}$</td>
<td>Pre-regulator Disable Voltage Range</td>
<td>Open drain/collector</td>
<td>-0.3</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>$I_{Pre_Disable}$</td>
<td>Pre-regulator Disable Voltage Range</td>
<td>Open Drain/collector</td>
<td>-1</td>
<td>1</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{Osc_Disable}$</td>
<td>Oscillator Disable Current</td>
<td>Open Drain/collector</td>
<td>-0.3</td>
<td>5</td>
<td>V</td>
</tr>
</tbody>
</table>

* Assumes inductive load, maximum current depends on die temperature – actual maximum current with be subject to switching frequency, bus voltage and thermals.

[3] EPC2038 datasheet
QUICK START GUIDE

DESCRIPTION

The Amplifier Board (EPC9507)

Figure 1 shows a diagram of the EPC9507 ZVS Class-D amplifier with pre-regulator. The pre-regulator is set to a specified DC current limit (up to 1.5 A) by adjusting P49 and operates from 8 V through 36 V input. The output voltage of the pre-regulator is limited to approximately 2 V below the input voltage. The pre-regulator can be bypassed by moving the jumper (JP60) over from the right 2 pins to the left 2 pins. To measure the current the amplifier is drawing, an ammeter can be inserted in place of the jumper (JP60) in the location based on the operating mode (pre-regulator or bypass).

The amplifier comes with its own oscillator that is pre-programmed to 6.78 MHz ± 678 Hz. It can be disabled by placing a jumper into J70 or can be externally shutdown using an externally controlled open collector / drain transistor on the terminals of J70 (note which is the ground connection). The switch needs to be capable of sinking at least 25 mA. An external oscillator can be used instead of the internal oscillator when connected to J71 (note which is the ground connection) and the jumper (JP70) is moved from the right 2 pins to the left 2 pins.

The pre-regulator can also be disabled in the same manner as the oscillator using J51. The pre-regulator can be bypassed, to increase the operating voltage (with no current or thermal protection) to the amplifier or to use an external regulator, by moving the jumper JP60 from the right 2 pins to the left 2 pins. Jumper JP60 can also be used to connect an ammeter to measure the current drawn by the amplifier (make sure the ammeter connects to the pins that correspond to the mode of operation either bypass or pre-regulator).

Single Ended Operation Hardware implementation

The amplifier can be configured for single ended operation where only devices Q1 and Q2 are used. In this mode only \(L_{ZVS1}\) and \(C_{ZVS}\) are used to establish ZVS operation. If a permanent single ended configuration is required and Q11 and Q12 are populated, then the following changes need to be made to the board:

1. Remove R77 and R78 OR P77 and P78
2. Short out C42_2 and C43_2
3. Short the connection of JMP1 (back side of the board)
4. Remove \(L_{ZVS1}\) (if populated)
5. Add \(L_{ZVS2}\) (390 nH)
6. Check that \(C_{ZVS}\) is populated, if not then install.
7. R71 and R72 may need to be adjusted for the new operating condition to achieve maximum efficiency (see section on ZVS timing adjustment).

ZVS Timing Adjustment

Setting the correct time to establish ZVS transitions is critical to achieving high efficiency with the EPC9507 amplifier. This can be done by selecting the values for R71, R72, R77, and R78 respectively. This procedure is best performed using potentiometers P71, P72, P77, and P78 installed that is used to determine the fixed resistor values. The procedure is the same for both single ended and differential mode of operation (as applicable per operating mode). The timing MUST initially be set WITHOUT the source coil connected to the amplifier. The timing diagrams are given in Figure 4 and should be referenced when following this procedure. Only perform these steps if changes have been made to the board as it is shipped preset.

The steps are:

1. Remove the jumper in JP60 and insert it into J51 to place the EPC9507 amplifier in bypass mode. With power off connect the main input power supply (+) bus to the center pin of JP60 (pin 2) and the ground of the main power to the ground (-) connection of J50 -V.
2. With power off, connect the control input power supply bus to +V (J90). Note the polarity of the supply connector.
3. Connect a LOW capacitance oscilloscope probe to the probe-hole J2 between the two eGaN FETs Q10_x and Q11_x and lean against the ground post as shown in Figure 3.
4. Turn on the control supply – make sure the supply is between 7 V and 12 V range (7.5 V is recommended).
5. Turn on the main supply voltage to the required predominant operating value (such as 24 V but NEVER exceed the absolute maximum voltage of 36 V).
6. While observing the oscilloscope adjust P71 or P77 for the rising edge of the waveform so achieve the green waveform of figure 4. Repeat for the falling edge of the waveform by adjusting P72 or P78. Repeat for the other eGaN FET pair if using differential mode operation.
7. Check that the setting remains optimal with a source coil attached. In this case it is important that the source coil is TUNED to resonance WITH an applicable load. Theoretically the settings should remain unchanged. Adjust if necessary.
8. Replace the potentiometers with fixed value resistors. Configure the EPC9507 amplifier back to normal operation by removing the power connection to J50 and JP60, removing the jumper in J51 and inserting it back into JP60 (right 2 pins 2 & 3).

Determining Component Values for \(L_{ZVS}\)

The ZVS tank circuit is not operated at resonance, and only provides the necessary negative device current for self-commutation of the output voltage at turn off. The capacitance \(C_{ZVS}\) is chosen to have a very small ripple voltage component and is typically around 1 μF. The amplifier supply voltage, switch-node transition time will determine the value of inductance for \(L_{ZVS}\), which needs to be sufficient to maintain ZVS operation over the DC coil load resistance range and coupling between the device and source coil range and can be calculated using the following equation:

\[
L_{ZVS} = \frac{\Delta t_n}{8 \cdot f_{sw} \cdot C_{OSS}}
\]  

(1)

Where:

\[\Delta t_n = \text{Voltage transition time [s]}\]

\[f_{sw} = \text{Operating frequency [Hz]}\]

\[C_{OSS} = \text{Charge equivalent device output capacitance [F]}\]

Note that the amplifier supply voltage \(V_{AMP}\) is absent from the equation as it is accounted for by the voltage transition time. The charge equivalent capacitance can be determined using the following equation:

\[
C_{OSS} = \frac{1}{V_{AMP}} \int_0^V C_{OSS} (v) \cdot dv
\]  

(2)

To add additional immunity margin for shifts in coil impedance, the value of \(L_{ZVS}\) can be decreased to increase the current at turn off of the devices (which will increase device losses). Typical voltage transition times range from 2 ns through 12 ns. For the differential case the voltage and charge (\(C_{OSS}\)) are doubled.
QUICK START GUIDE

QUICK START PROCEDURE

The EPC9507 amplifier board is easy to set up and evaluate the performance of the eGaN FET in a wireless power transfer application.

The EPC9507 can be operated using any one of two alternative methods:

a. Using the pre-regulator
b. Bypassing the pre-regulator

a. Operation using the pre-regulator

The pre-regulator is used to supply power to the amplifier in this mode and will limit the DC current to the amplifier based on the setting. The pre-regulator also monitors the temperature of the amplifier and will limit the current in the event the temperature exceeds 85°C.

1. Make sure the entire system is fully assembled prior to making electrical connections and make sure jumper (JP60 is set to pre-regulator – right 2 pins).
2. With power off, connect the main input power supply bus to +V_in (J50). Note the polarity of the supply connector.
3. With power off, connect the control input power supply bus to +V_cont (J90). Note the polarity of the supply connector.
4. Select and connect an applicable load resistance to the device board.
5. Make sure all instrumentation is connected to the system.
6. Turn on the control supply – make sure the supply is between 7 V and 12 V (7.5 V is recommended).
7. Turn on the main supply voltage to the required value (it is recommended to start at 8 V and do not exceed the absolute maximum voltage of 32 V).
8. Once operation has been confirmed, adjust the main supply voltage within the operating range and observe the output voltage, efficiency and other parameters on both the amplifier and device boards.
9. For shutdown, please follow steps in the reverse order. Start by reducing the main supply voltage to 0 V followed by steps 6 through 2.

NOTE: When measuring the high frequency content switch-node (Source Coil Voltage), care must be taken to avoid long ground leads. An oscilloscope probe connection (preferred method) has been built into the board to simplify the measurement of the Source Coil Voltage (J2 and J3 as shown in Figure 3).

b. Operation bypassing the pre-regulator

In this mode, the pre-regulator is bypassed and the main power is connected directly to the amplifier. This allows the amplifier to be operated using an external regulator or to test at higher voltages.

In this mode there is no current or thermal protection for the eGaN FETs.

1. Make sure the entire system is fully assembled prior to making electrical connections and remove the jumper JP60 and insert it into J51 to place the EPC9507 amplifier in bypass mode. Never connect the main power positive (+) to J50 when operating in bypass mode.
2. With power off, connect the main input power supply ground to the ground terminal of J50 (-) and the positive (+) to the center pin of JP60.
3. With power off, connect the control input power supply bus to +V_cont (J90). Note the polarity of the supply connector.
4. Select and connect an applicable load resistance to the device board.
5. Make sure all instrumentation is connected to the system.

THERMAL CONSIDERATIONS

The EPC9507 demonstration system showcases the EPC2007C and EPC2038 eGaN FETs in a wireless energy transfer application. Although the electrical performance surpasses that of traditional silicon devices, their relatively smaller size does magnify the thermal management requirements. The operator must observe the temperature of the gate driver and eGaN FETs to ensure that both are operating within the thermal limits as per the datasheets.

NOTE: The EPC9507 demonstration system has limited current and thermal protection only when operating off the Pre-Regulator. When bypassing the pre-regulator there is no current or thermal protection on board and care must be exercised not to over-current or over-temperature the devices. Wide coil coupling and load range variations can lead to increased losses in the devices.

Pre-Cautions

The EPC9507 demonstration system has no controller or enhanced protections systems and therefore should be operated with caution. Some specific precautions are:

1. Please contact EPC at info@epc-co.com should the tuning of the coil be required to change to suit specific conditions so that it can be correctly adjusted for use with the ZVS Class-D amplifier.
2. There is no heat-sink on the devices and during experimental evaluation it is possible present conditions to the amplifier that may cause the devices to overheat. Always check operating conditions and monitor the temperature of the EPC devices using an IR camera.
Figure 1: Diagram of EPC9507 Amplifier Board

7 - 12 V\text{DC} 
Gate Drive and 
Control Supply
(Note Polarity)

6 - 36 V\text{DC} 
V_{\text{IN}} 
Supply
(Note Polarity)

Figure 2: Proper Connection and Measurement Setup for the Amplifier Board

Enable Pre-Regulator Jumper

Disable Pre-Regulator Jumper

Pre-Regulator Timing Setting
(Not Installed)

Amplifier Timing Setting
(Not Installed)

Pre-Regulator Current Setting

Oscillator Selection Jumper

External / Internal

External Oscillator

Switch-Node Main Oscilloscope Probe

Source Coil Connection

Ground Post

Switch-Node Secondary Oscilloscope Probe

Bypass Mode Connection

Pre-Regulator Jumper

Coil Connection

Single Ended Operation Jumper

Enable Oscillator

Disable Oscillator

Voltage Source Jumper
Figure 3: Proper Measurement of the Switch Nodes Using the Hole and Ground Post

Figure 4: ZVS Timing Diagrams
### Table 3: Bill of Materials - Amplifier Board

<table>
<thead>
<tr>
<th>Item</th>
<th>Qty</th>
<th>Reference</th>
<th>Part Description</th>
<th>Manufacturer</th>
<th>Part #</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>2</td>
<td>C1_1, C1_2</td>
<td>Capacitor, Ceramic, 4.7 µF, ±20%, 10 V, X5R</td>
<td>Samsung</td>
<td>CL05A475MPSNRRNC</td>
</tr>
<tr>
<td>2</td>
<td>2</td>
<td>C52, C60</td>
<td>Capacitor, Ceramic, 4.7 µF, ±10%, 16 V, X5R</td>
<td>TDK</td>
<td>C1608XR1C475X080AC</td>
</tr>
<tr>
<td>3</td>
<td>7</td>
<td>C15_1, C15_2, C16_1, C16_2, C5_2, C5_2</td>
<td>Capacitor, Ceramic, 2.2 µF, ±10%, 100 V, X7R</td>
<td>Taiyo Yuden</td>
<td>HMK32S7225KN-T</td>
</tr>
<tr>
<td>4</td>
<td>1</td>
<td>C50</td>
<td>Capacitor, Ceramic, 1 µF, ±10%, 50 V, X7R</td>
<td>Taiyo Yuden</td>
<td>UM107A87105KA-T</td>
</tr>
<tr>
<td>5</td>
<td>2</td>
<td>Czvs1, Czvs2</td>
<td>Capacitor, Ceramic, 1.0 µF, 100 V, ±10%, X7S</td>
<td>TDK</td>
<td>CGA43X752A105K125AE</td>
</tr>
<tr>
<td>6</td>
<td>3</td>
<td>C90, C91, C92</td>
<td>Capacitor, Ceramic, 1.0 µF, 25 V, ±10%, X5R</td>
<td>Murata</td>
<td>GRM188R61E105KA122D</td>
</tr>
<tr>
<td>7</td>
<td>6</td>
<td>C71, C72, C77, C78, C80, C81</td>
<td>Capacitor, Ceramic, 100 nF, ±10%, 25 V, X5R</td>
<td>Murata</td>
<td>C1005X7R1E104K080BB</td>
</tr>
<tr>
<td>8</td>
<td>9</td>
<td>C2_1, C2_2, C4_1, C4_2, C5_1, C5_2, C5_2, C5_7, C63, C70</td>
<td>Capacitor, Ceramic, 100 nF, ±10%, 25 V, X5R</td>
<td>TDK</td>
<td>C1005X7S2A103M050BB</td>
</tr>
<tr>
<td>9</td>
<td>2</td>
<td>C3_1, C3_2, C4_1, C4_2, C5_1, C5_2, C5_7, C63, C70</td>
<td>Capacitor, Ceramic, 100 nF, ±10%, 25 V, X5R</td>
<td>TDK</td>
<td>C1005X7S2A103M050BB</td>
</tr>
</tbody>
</table>

(continued on next page)
# Table 3: Bill of Materials - Amplifier Board (continued)

<table>
<thead>
<tr>
<th>Item</th>
<th>Qty</th>
<th>Reference</th>
<th>Part Description</th>
<th>Manufacturer</th>
<th>Part #</th>
</tr>
</thead>
<tbody>
<tr>
<td>45</td>
<td>2</td>
<td>Q4_1, Q4_2</td>
<td>eGaN® FET, 100 V, 0.5 A, 2.8 Ω</td>
<td>EPC</td>
<td>EPC2038</td>
</tr>
<tr>
<td>46</td>
<td>1</td>
<td>U90</td>
<td>IC's, 5 V LDO, 250 mA, up to 16 V in, V_{input} = 0.33 V @ 250 mA</td>
<td>Microchip</td>
<td>MCP1703T-5002E/MC</td>
</tr>
<tr>
<td>47</td>
<td>3</td>
<td>U1_1, U1_2, U60</td>
<td>IC's, Gate Driver, 5.2 VDC, 1.2 A, 4.5 V to 5.5 V</td>
<td>Texas Instruments</td>
<td>LM5113TME/NOPB</td>
</tr>
<tr>
<td>48</td>
<td>1</td>
<td>U50</td>
<td>IC's, Step Down Controller, 1.07 MHz, 6 V to 36 V</td>
<td>Linear Technologies</td>
<td>LT3741EU#PBF</td>
</tr>
<tr>
<td>49</td>
<td>3</td>
<td>U71, U77, U81</td>
<td>IC's, Logic 2 NAND Gate, 1.65 V to 5.5 V, ±24 mA</td>
<td>Fairchild</td>
<td>NC7S200L6X</td>
</tr>
<tr>
<td>50</td>
<td>3</td>
<td>U72, U78, U80</td>
<td>IC's, 2 Input NAND Gate, Tiny Logic, 1.65 V to 5.5 V, ±32 mA</td>
<td>Fairchild</td>
<td>NC7S08L6X</td>
</tr>
<tr>
<td>51</td>
<td>1</td>
<td>U70</td>
<td>IC's, Programmable Oscillator 1.5 to 60 MHz, V_{in} = 1.8 V/2.5 V/2.8 V/3.0 V/3.3 V/5.0 V</td>
<td>EPSON</td>
<td>SG-8002CE-PHB</td>
</tr>
<tr>
<td>52</td>
<td>2</td>
<td>TP1, TP2</td>
<td>Test Point, Test Point Subminiature</td>
<td>Keystone</td>
<td>5015</td>
</tr>
<tr>
<td>53</td>
<td>0.5</td>
<td>GP1_1, GP1_2, J61, J51, JP60, J70, J71, J75, JP70, J90 (See Note 1)</td>
<td>Header, Male Vertical, 36 Pin. 230° Contact Height, .1&quot; Center Pitch</td>
<td>FCI</td>
<td>68001-236HLF</td>
</tr>
<tr>
<td>54</td>
<td>1</td>
<td>J1</td>
<td>Connector, RP-SMA Plug, 50 Ω</td>
<td>Linx</td>
<td>CONREVSM013.062</td>
</tr>
<tr>
<td>55</td>
<td>1</td>
<td>J50</td>
<td>Connector, Male Locking Header, WR-WTB 3.96 mm., 150° Center to Center Pitch 2 pin</td>
<td>Würth</td>
<td>645 002 114 822</td>
</tr>
</tbody>
</table>

## Optional Components

<table>
<thead>
<tr>
<th>Item</th>
<th>Qty</th>
<th>Reference</th>
<th>Part Description</th>
<th>Manufacturer</th>
<th>Part #</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>1</td>
<td>C73</td>
<td>Capacitor, DNP 22 pF, 25 V</td>
<td>DNP</td>
<td>DNP</td>
</tr>
<tr>
<td>2</td>
<td>7</td>
<td>P49, P71, P72, P77, P82, P83</td>
<td>Potentiometer, DNP 1 k, 10 k</td>
<td>DNP</td>
<td>DNP</td>
</tr>
<tr>
<td>3</td>
<td>2</td>
<td>Lzvs1, Lzvs2</td>
<td>Inductor, DNP</td>
<td>DNP</td>
<td>DNP</td>
</tr>
<tr>
<td>4</td>
<td>2</td>
<td>JMP1, JP61</td>
<td>Jumper, DNP Jumper with Test Point 1X2 Pin 0.100&quot; Pitch</td>
<td>DNP</td>
<td>DNP</td>
</tr>
</tbody>
</table>

EPC would like to acknowledge Würth Electronics (www.we-online.com/web/en/wuerth_elektronik/start.php) for their support of this project.

Note 1: (36 pin Header to be cut as follows) (18)
(18) cut 1 pin
(J61) cut 2 pins
(J90) cut 3 pins
Figure 5: EPC9507 ZVS Class-D Amplifier Schematic
Rev 3.2
Figure 6: EPC9507 Pre-Regulator Schematic
Figure 7: EPC9507 Pre-Regulator Schematic
For More Information:

Please contact info@epc-co.com or your local sales representative

Visit our website:
www.epc-co.com

Sign-up to receive EPC updates at bit.ly/EPCurdates or text “EPC” to 22828

Demonstration Board Warning and Disclaimer

The EPC9507 board is intended for product evaluation purposes only and is not intended for commercial use. Replace components on the Evaluation Board only with those parts shown on the parts list (or Bill of Materials) in the Quick Start Guide. Contact an authorized EPC representative with any questions.

This board is intended to be used by certified professionals, in a lab environment, following proper safety procedures. Use at your own risk.

As an evaluation tool, this board is not designed for compliance with the European Union directive on electromagnetic compatibility or any other such directives or regulations. As board builds are at times subject to product availability, it is possible that boards may contain components or assembly materials that are not RoHS compliant. Efficient Power Conversion Corporation (EPC) makes no guarantee that the purchased board is 100% RoHS compliant.

The Evaluation board (or kit) is for demonstration purposes only and neither the Board nor this Quick Start Guide constitute a sales contract or create any kind of warranty, whether express or implied, as to the applications or products involved.

Disclaimer: EPC reserves the right at any time, without notice, to make changes to any products described herein to improve reliability, function, or design. EPC does not assume any liability arising out of the application or use of any product or circuit described herein; neither does it convey any license under its patent rights, or other intellectual property whatsoever, nor the rights of others.

EPC Products are distributed through Digi-Key.
www.digikey.com